IFW

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Tsuyoshi NISHIZAWA Group Art Unit: 1722

Application No.: 10/561,957 Examiner: S. MALEKZADEH

Filed: December 22, 2005 Docket No.: 126273

For: METHOD FOR PRODUCING SILICON EPITAXIAL WAFER AND SILICON

EPITAXIAL WAFER

AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In reply to the April 3, 2007 Office Action, please consider the following:

Amendments to the Claims as reflected in the listing of claims; and

Remarks.